

# Radar Pulsed Power Transistor, 100W, 2ms Pulse, 20% Duty 1.2 - 1.4 GHz

## PH1214-100EL

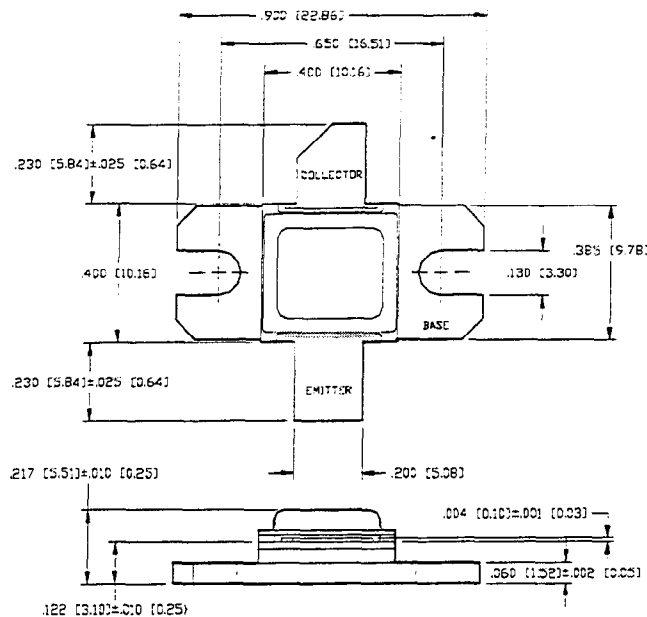
V2.01

### Features

- NPN Silicon Microwave Power Transistor
- Common Base Configuration
- Broadband Class C Operation
- High Efficiency Interdigitated Geometry
- Diffused Emitter Ballasting Resistors
- Gold Metalization System
- Internal Input Impedance Matching
- Hermetic Metal/Ceramic Package

### Absolute Maximum Ratings at 25°C

| Parameter                 | Symbol    | Rating      | Units |
|---------------------------|-----------|-------------|-------|
| Collector-Emitter Voltage | $V_{CES}$ | 75          | V     |
| Emitter-Base Voltage      | $V_{EBO}$ | 3.0         | V     |
| Collector Current (Peak)  | $I_C$     | 14.1        | A     |
| Total Power Dissipation   | $P_{TOT}$ | 214         | W     |
| Junction Temperature      | $T_J$     | 200         | °C    |
| Storage Temperature       | $T_{STG}$ | -65 to +200 | °C    |



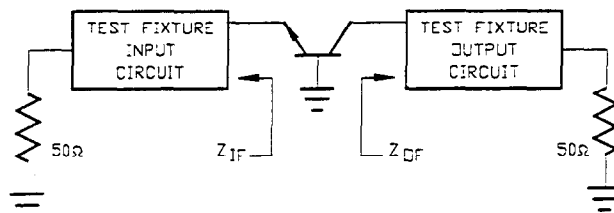
UNLESS OTHERWISE NOTED, TOLERANCES ARE  
INCHES ±0.005 MILLIMETERS ±0.13MM

### Electrical Characteristics at 25°C

| Parameter                           | Symbol       | Min | Max   | Units | Test Conditions  |
|-------------------------------------|--------------|-----|-------|-------|--|
| Collector-Emitter Breakdown Voltage | $BV_{CES}$   | 75  | -     | V     | $I_C=50$ mA  |
| Collector-Emitter Leakage Current   | $I_{CES}$    | -   | 10    | mA    | $V_{CE}=28$ V  |
| Thermal Resistance                  | $R_{TH(JC)}$ | -   | 0.7   | °C/W  | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Output Power                        | $P_{OUT}$    | 100 | -     | W     | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Power Gain                          | $G_P$        | 6.0 | -     | dB    | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Collector Efficiency                | $\eta_C$     | 52  | -     | %     | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Input Return Loss                   | RL           | 8   | -     | dB    | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Overdrive Stability                 | OD-S         | -   | +1.0  | dB    | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Load Mismatch Tolerance             | VSWR-T       | -   | 3:1   | -     | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |
| Load Mismatch Stability             | VSWR-S       | -   | 1.5:1 | -     | $V_{CC}=28$ V, $P_{IN}=25$ W, $F=1.20, 1.30, 1.40$ GHz |

### Broadband Test Fixture Impedances

| F(GHz) | $Z_{IF}(\Omega)$ | $Z_{OF}(\Omega)$ |
|--------|------------------|------------------|
| 1.20   | 2.6 - j3.8       | 3.0 - j2.7       |
| 1.30   | 3.0 - j3.4       | 2.4 - j2.6       |
| 1.40   | 3.4 - j3.1       | 1.9 - j2.5       |



Specifications Subject to Change Without Notice.

9-140

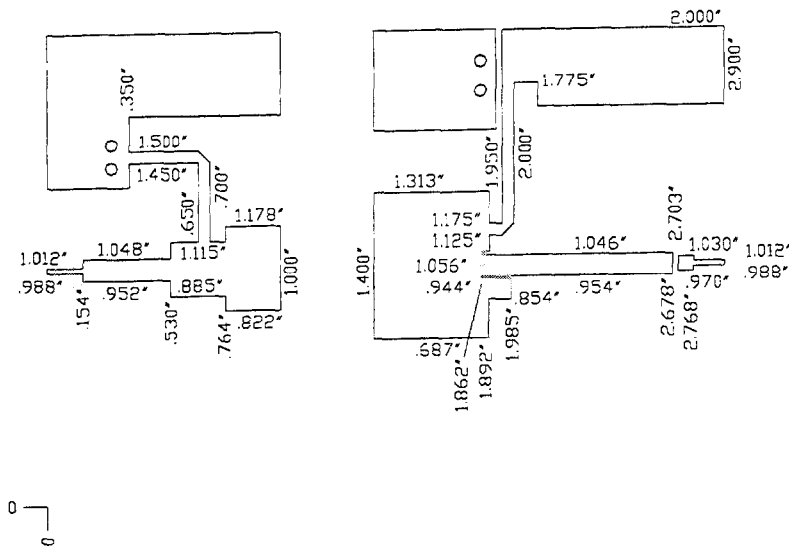
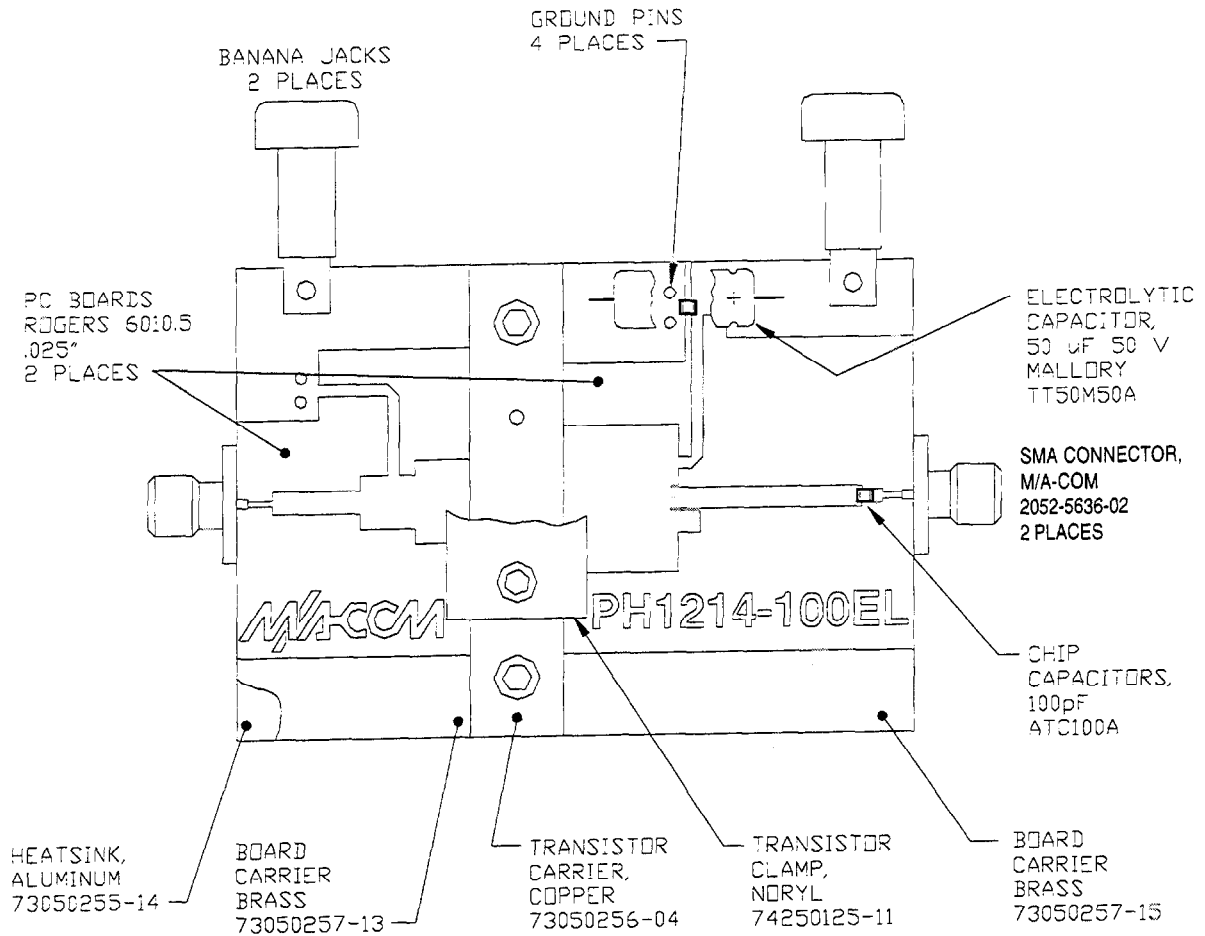
MA-COM, Inc.

North America: Tel. (800) 366-2266  
Fax (800) 618-8883

Asia/Pacific: Tel. +81 (03) 3226-1671  
Fax +81 (03) 3226-1451

Europe: Tel. +44 (1344) 869 595  
Fax +44 (1344) 300 020

RF Test Fixture



CIRCUIT DIMENSIONS

Specifications Subject to Change Without Notice.

M/A-COM, Inc.

North America: Tel. (800) 366-2266  
Fax (800) 618-8883

Asia/Pacific: Tel. +81 (03) 3226-1671  
Fax +81 (03) 3226-1451

Europe: Tel. +44 (1344) 869 595  
Fax +44 (1344) 300 020